## **Amendments to the Specification:**

Please replace the paragraph beginning at page 20, line 10, with the following amended paragraph:

**Figs.** <u>4A-4C</u> <u>4A-4D</u> are cross-sectional views of the epitaxial junction isolation (epi-JI) of CMOS, bipolar and DMOS components using deep "down-only" isolation diffusions;

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